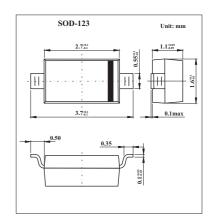
SMD Type Diodes

SMALL SIGNAL DIODES 1N4150W

■ Features

- Silicon Epitaxial Planar Diode
- Fast general purpose and switching.
- This diods is also available in other case styles including: the DO-35 case with the type designation 1N4150 and the Mini-MELF case with the type disignation LL4150.



■ Absolute Maximum Ratings Ta = 25°C

Paramater	Symbol	Value	Unit
Peak Reverse voktage	VRM	50	V
Maximum Average Rectified Current	lo	200	mA
Maximum Power Dissipation at Tamb = 25 $^{\circ}\mathrm{C}$	Ptot	410 ⁽¹⁾	mW
Maximum Forward Voltage Drop at IF = 200mA	VF	1.0	V
Maximum Reverse Current at VR = 50 V	lr	100	nA
Maximum Reverse Recovery Time at IF = 10 to 200 mA, to 0.1 IF	Trr	4.0	ns
Maximum Junction Temperature	Tj	150	$^{\circ}$
Storage Temperature Range	Ts	-65 to+150	$^{\circ}$

NOTES::

(1) Valid provided that electrodes are kept at ambient temperature